MSC.56P TEMPERATURE DEPENDENCE OF THE OPTICAL GAP CuGasSes

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The investigation of the absorption coefficient spectra below the fundamental edge of ordered vacancy compound CuGa₅Se₈ was studied early for samples prepared by Bridgman method [1]. Compositional measurements were carried out by Energy Dispersive X-ray Microanalysis (EDAX). Samples have stoichiometric compositions of Cu:Ga:Se as 7: 35.4: 57.5 atomic percentage, practically equal to 1:5:8.

The optical transmittance spectra in the spectral range 600–900 nm were measured with MDR2 monochromator using halogen lamp as a light source. The transmitted radiation was detected by a Ge photodetector and Unipan amplifier. The temperature interval between 10 and 300K was supplied by close cycle helium Leybold system.

For direct band gap semiconductors $\alpha(hv) = A(hv - Eg)^{1/2}$ where hv is the characteristic energy of a photon, A is a temperature independent constant that depends on the effective mass and the refractive index. Linear dependence near the band edge confirms that $CuGa_5Se_8$ has direct fundamental band gap. From the extrapolation of $(\alpha hv)^2$ versus hv curves to $(\alpha hv)^2 = 0$, the value of E_g is equal to 1.76 at 300 K. Reported value of E_g is about 1.81eV[1] and 1.78 eV[2].

Three-parameter thermodynamic model of O'Donnell and Chen[3], the Einstein model[4] and the Passler model[5] have been employed to describe the temperature variation of the energy gap. By fitting these model to our data of $E_g(T)$, estimated on the base of the linear extrapolation method the following set of parameters was obtained: $E_g(0)$ is the band gap at T=0 K, $\langle E_{ph} \rangle$ is an effective phonon energy, Θ is an effective phonon temperature, S is a dimensionless constant related to the electron–phonon coupling, K is a temperature-independent constant and Σ is the Einstein temperature.

Acknowledgments

Financial support from INTAS program (Project 03-51-6314) are acknowledged.

One of us (S.Levcenco) would like to thank the World Federation of Scientists for financial support.

References

- 1. G. Marin, S.M. Wasim, C. Rincon, G. Sanchez Perez, P. Bocaranda. J. Appl. Phys. 95 8280 (2004).
- 2. G. Marin, R. Marquez, R. Guevara, S.M. Wasim, J.M. Delgado, C. Rincon, G. Sanchez Perez, I. Molina, and P. Bocaranda., *Jpn. J. Appl. Phys.* **39-1**,44(2000).
- 3 O'Donnel K P and Chen X 1991 Appl. Phys. Lett. **58** 2924.
- 4 Z. Yang, K. P. Homewood, M. S. Finney, M. A. Harry and J. Reeson, J. Appl. Phys. 78, 1958 (1995).
- 5 R. Pässler, *Phys. Status Solidi* B **200**, 155 (1997).